## YJ Planar Schottky Barrier Diode Die Specification

30V 0.5A, 23mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB023L030AS-180A

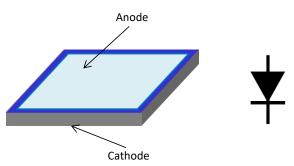
## **Main Products Characterstics**

• Average forward current: IF(AV) = 0.5 A

• Maximum operating junction temperature: Tj = 125 °C

• ESD rating: >2KV, per IEC61000-4-2 (Contact Discharge)

• Top metal: AL/3.5um



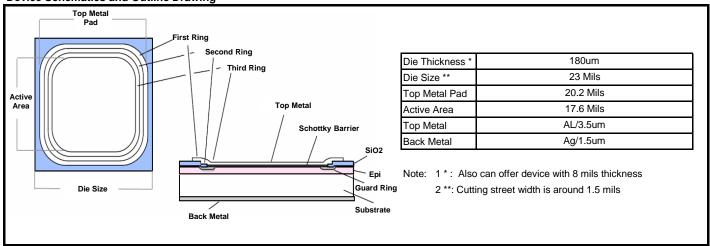
**Maximum Ratings** 

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Parameter	Symbol	Rating			
Repetitive peak reverse voltage	$V_{RRM}$	30 V			
Average forward current	I <sub>F(AV)</sub>	0.5 A			
Non-repetitive peak surge current (tp = 8.3 ms, halfwave, 1 cycle)	I <sub>FSM</sub>	10 A			
Storage temperature range	$T_{stg}$	-50 to +125 °C			
Maximum operating junction temperature	Tj	125 °C			

Static Electrical Characteristics (Ta = 25°C)

Parameter	Symbol	Value	
r ai ailletei		Spec	Typical
Reverse breakdown voltage $I_R = 0.1 \text{mA}$	$V_{BR}$	40 V	44V
Maximum forward voltage drop	.,	0.3V/0.36V/	0.28V/0.35V/
$I_F = 0.01A//0.1A/0.2A/0.5A$ Pulse Test: tp = 300 μs, δ ≤ 2%	V <sub>F</sub>		0.39V/0.44V
Maximum reverse current $V_R = 25V$ Pulse Test: tp = 300 $\mu$ s, $\delta \le 2\%$	I <sub>R</sub>	50uA	3.5uA

**Device Schematics and Outline Drawing** 



## **Important Notice**

Specification apply to die only. Actual performance may degrade when assembled.

Yangjie Electronics does not guarantee device performance after assembly.

All operating parameters must be validated for each customer application by customer's technical experts.

Data sheet information is subjected to change without notice.

Recommended Storage Environment:

Store in original container, in dessicated nitrogen, with no contamination.

Shelf life for parts stored in above condition is 2 years.

If the storage is done in normal atmosphere shelf life is reduced to 6 months.

扬州扬杰电子科技股份有限公司 Yangzhou Yangjie Electronics Technology Co.,Ltd. 电话: 0514-80982389 传真: 0514-80980189

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